

Basavarajeswari Group of Institutions  
**BALLARI INSTITUTE OF TECHNOLOGY & MANAGEMENT**  
 (Autonomous Institute under Visvesvaraya Technological University, Belagavi)

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Course Code 

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Third Semester B.E. Degree Examinations, September / October 2024

**ANALOG ELECTRONIC CIRCUITS**

Duration: 3 hrs

Max. Marks: 100

Note: 1. Answer any FIVE full questions, choosing ONE full question from each module.  
 2. Missing data, if any, may be suitably assumed

<u>Q. No</u>	<u>Question</u>	<u>Marks</u>	<u>(RBTL:CO:PI)</u>
<b>MODULE – 1</b>			
1.	a. Describe the characteristics of pn-junction with necessary equations.	06	(1 : 1 : 1.3.1)
	b. Explain the half wave rectifier with circuit diagram, necessary waveforms and calculate efficiency for the same.	08	(2 : 1 : 1.3.1)
	c. Explain the construction and operation of Bipolar Junction Transistor (BJT) with carrier flow diagram.	06	(2 : 1 : 1.3.1)
<b>OR</b>			
2.	a. Explain in detail about the negative series clipper with circuit diagram and necessary waveform.	04	(1 : 1 : 1.3.1)
	b. Define voltage regulator and explain different types of voltage regulators.	10	(2 : 1 : 1.3.1)
	c. Explain the construction and operation of MOSFET.	06	(2 : 1 : 1.3.1)
<b>MODULE – 2</b>			
3.	a. Explain the voltage divider biasing for BJT using a single power supply. How does $R_E$ provide a negative feedback action to stabilize the bias current with necessary supporting mathematical equations?	08	(2 : 2 : 1.3.1)
	b. Draw the small signal equivalent circuit model for MOSFET and obtain the expression for voltage gain and transconductance.	08	(2 : 2 : 1.3.1)
	c. A BJT having $\beta=120$ is biased at DC collector current of 1mA. Find the Value of $g_m$ , $r_e$ and $r_\pi$ at the bias point.	04	(3 : 2 : 2.1.2)
<b>OR</b>			
4.	a. Explain biasing of MOSFET by fixing $V_{GS}$ .	04	(2 : 2 : 1.3.1)
	b. Derive the following relation with respect to small signal operation of BJT: (i) Input resistance (ii) Emitter resistance Also derive the relation between emitter and base resistance.	08	(2 : 2 : 1.3.1)
	c. For the circuit shown in Fig. Q4 (c), find the required value of $V_{GS}$ to establish a dc bias current $I_D = 0.5$ mA. Device parameters are: $V_t=1V$ , $K_n' \left( \frac{W}{L} \right) = 1 \text{ mA/V}^2$ and $\lambda=0$ . What is the percentage change in $I_D$ obtained when transistor is replaced with another having $V_t = 1.5V$ .	08	(3 : 2 : 2.1.2)

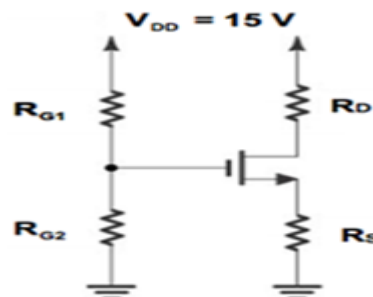


Fig. Q4(c)

### MODULE – 3

5. a. With the neat circuit diagram and AC equivalent circuit, derive the expression for  $R_{in}$ ,  $A_{vo}$ ,  $A_v$  and  $R_o$  for a source follower. **08** (2 : 3 : 1.3.1)
- b. With mathematical equations, explain the different internal capacitances in the MOSFET. **06** (2 : 3 : 1.3.1)
- c. For the n-channel MOSFET with  $t_{ox}=10$  nm,  $L=1\mu\text{m}$ ,  $W=10\mu\text{m}$ ,  $L_{OV} = 0.05\mu\text{m}$ ,  $C_{sbo} = C_{dbo}=10$  pF,  $V_O = 0.6$  V,  $V_{SB} = 1$  V and  $V_{DS} = 2$  V. Calculate i)  $C_{OX}$  ii)  $C_{OV}$  iii)  $C_{gs}$  iv)  $C_{gd}$  v)  $C_{sb}$  vi)  $C_{db}$  **06** (3 : 3 : 2.1.2)

**OR**

6. a. A Common Source amplifier utilizes a MOSFET biased at  $I_D=0.25$  mA with  $V_{OV}=0.25$  V and  $R_D=20$  K $\Omega$ . The device has  $V_A= 50$  V. The amplifier is fed with source having  $R_{sig}=100$  K $\Omega$  and a  $20$  K $\Omega$  load is connected to the output. Find  $R_{in}$ ,  $A_{vo}$ ,  $G_v$ ,  $A_v$  and  $R_o$ . If to maintain reasonable linearity, the peak of the input sine wave signal is limited to 10% of  $(2V_{ov})$  what is the peak of the sine wave voltage at the output? **10** (2 : 3 : 2.1.2)
- b. Write a Short note on: (i) Current Source (ii) Current Mirror **10** (3 : 3 : 1.3.1)

### MODULE – 4

7. a. Determine the voltage gain, input and output impedance with feedback for a voltage series feedback amplifier having  $A= -100$ ,  $R_i=10$  K $\Omega$ ,  $R_o=20$  K $\Omega$  for the feedback of (i)  $\beta= 1$  and (ii)  $\beta= -0.5$ . **10** (3 : 4 : 2.1.2)
- b. Explain the four basic Feedback topologies. **10** (2 : 4 : 1.3.1)

**OR**

8. a. Explain the operation of Class B amplifier. Prove that the maximum conversion efficiency of Class B transformer coupled amplifier is 78.5%. **10** (3 : 4 : 1.3.1)
- b. What is output stage and discuss the classification of output stages based on the Collector current? **10** (2 : 4 : 1.3.1)

### MODULE – 5

9. a. What is an instrumentation amplifier? Explain an instrumentation amplifier. **10** (2 : 5 : 1.3.1)
- b. Explain the operation of monostable multivibrator with relevant diagram and waveform. **10** (2 : 5 : 1.3.1)

**OR**

10. a. What is R-2R network type DAC? Explain with relevant expression. **10** (2 : 5 : 1.3.1)
- b. Design an Astable Multivibrator using 555 timer with **10** (2 : 5 : 1.3.1)
- (i)  $f_0 = 1$  kHz and Duty Cycle = 40% (ii)  $f_0 = 2$  kHz and Duty Cycle = 50% (iii)  $f_0 = 1$  kHz and Duty Cycle = 70%
- Assume  $C = 0.01\mu\text{F}$  for all cases.

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